Supporting Information

Design of light-sensitive tubular MoS₂/C composite as the cathode for photo-enhanced rechargeable zinc-ion battery

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1. Supplemental Experimental Procedures

1.1 Photo-responsive solid-state zinc-ion device

In this device, the gel electrolyte was prepared by dissolving 1.0 g polyvinyl alcohol (PVA, Mw: ~89000-98000) in 20 mL ZnSO₄ aqueous solution (2 M) under vigorous stirring at 90 °C for 2 h. The cathode was fabricated by coating MoS₂/C-NT slurry on the PET/ITO substrate and Zn foil act as anodes (mass loading: 2 mg cm⁻²). The photo-responsive solid-state zinc-ion battery (PRZB) was assembled by sandwiching a gel electrolyte film of ZnSO₄- (PVA) between metal Zn and MoS₂/C-NT electrodes. The device was further sealed with 3M tape to prevent any gel electrolyte leakage. Cu conductive adhesive tape was tightly pasted to the margins of these electrodes.

1.2 Calculation of capacitive contribution in total capacitance

The contribution of the capacitive-controlled reaction can be estimated according to the following equations proposed by Dunn.

$$i(v) = k_1 v + k_2 v^{1/2} \quad (1)$$

where i is the current (A g^{-1}), v is the scan rate (mV s⁻¹), and k₁v and k₂v^{1/2} correspond to the capacitive and diffusion contributions, respectively. The surface-controlled capacitance also reflects the rate performance of the electrode materials as well as the surface charge storage capability.

1.3 Calculation of conduction band

Generally, the hydrogen reduction potential is at 4.5 eV below the vacuum level. Therefore, the MoS_2 edge positions related to the vacuum level can be expressed empirically by the following equation:¹

$$E_{CB} = E_{VB} + E_g \quad (2)$$

The calculated edge positions of VB_{MoS_2} and CB_{MoS_2} were -3.59 eV (vs. vacuum) and -1.69 eV (vs. vacuum), respectively.

1.4 Calculation of photo-conversion efficiency

To demonstrate the contribution of photo-regulation in the photo-electrochemical coupling process, photo-conversion efficiency has been calculated by the following equation:²

$$\eta = \frac{E_S S_1}{P_{in} t s_2} \times 100\% \tag{3}$$

where η represents the photo-conversion efficiency, E_S is the areal energy density at a specific current of 0.1 mA cm⁻², S_1 is the photo positive electrode area, P_{in} is the photo-power density, t is the charging time under illuminated condition, and S_2 is the illuminated surface area. As a result, the photo-conversion efficiency was calculated to be 0.98 % according to the experimental parameters.



Fig. S1 UV–vis absorption spectrum (a) and Tauc plot of MoS_2 (b) and valence band XPS spectra (c).



Fig. S2 SEM images of g-C₃N₄-NT (a) and MoS₂ (b), HRTEM image of MoS₂/C-NT (c), and SEM element mapping (d-i).



Fig. S3 HRTEM image of $MoS_2/C-NT$ (a) and TEM image of $MoS_2(b)$.



Fig. S4 XRD patterns of MoS₂/C-NT after light illumination.



Fig. S5 Raman spectra of MoS₂ and MoS₂/C-NT with different range of Raman shift (300-420cm⁻¹) (a) and (1200-1800cm⁻¹) (b) and N₂ adsorption-desorption isotherm (inset: pore size distribution) (c).



Fig. S6 XPS survey spectrum of MoS₂/C-NT.



Fig. S7 High resolution XPS spectra of (a) Mo 3d and (b) S 2p of the MoS₂.



Fig. S8 CV curves of the photo-ZIBs at scan rates of 0.2 mV s⁻¹ (a), 0.4 mV ⁻¹ (b), 0.6 mV s⁻¹ (c) and 0.8 mV s⁻¹ (d) in dark and illuminated states.



Fig. S9 Capacitive contribution determinations to charge storage at 0.8 mV s⁻¹ under illuminated conditions.



Fig. S10 Galvanostatic charge–discharge curves of MoS₂/C-NT at current densities of 0.2-2 A g⁻¹ (a) and cycling performance of MoS₂/C-NT at 1A g⁻¹ (b) under light



Fig. S11 Long-term cycling test of the MoS_2/C -NT and MoS_2/C at a specific current

of 500 mA g^{-1} in dark.



Fig. S12 SEM images of the cycled photocathode for 200 cycles under light condition.

GITT measurements:

During GITT test, the cell was discharged and charged at 0.1 A g⁻¹ for 15min, and then relaxed for 30 min to allow the voltage to reach equilibrium. The Zn^{2+} diffusion coefficient (D_{Zn}^{2+}) can be calculated by the following equation:³

$$D = \frac{4}{\pi t} \left(\frac{\mathrm{m}_{B} V_{M}}{M_{B} S} \right)^{2} \left(\frac{\Delta E_{\mathrm{s}}}{\Delta E_{\tau}} \right)^{2}$$

Where V_M , M_B , m_B and S represent the molar volume of the active material, molar mass of the active material, mass of the active material and contact surface area of the anode, respectively; τ represents the relaxation time, and ΔEs and $\Delta E\tau$ are the voltage difference during the pulse time and constant current charge/discharge process.



Fig. S13 Discharge/charge GITT profiles at 0.1 A g^{-1} and the corresponding Zn^{2+} diffusion coefficients of MoS₂/C-NT.

Positive electrode	Battery System	Current	Discharge	Photo power	to power lensity (w cm ⁻²) Cycling stability	Conversion	Battery
		density	capacity	density		efficiency	Туре
		(mA g ⁻¹)	$(mA h g^{-1})$	(Mw cm ⁻²)		(%)	
N719	Li	C/24		100	15	0.06.0.08	Coin cell
dye/LiFePO ₄ ⁴						0.00-0.08	
$(C_6H_9C_2H_4NH_3)_2$	Li	40	~90-100	100	10	0.034	pouch cell
PbI ₄ ⁵						0.054	
TiO ₂ /dye/Cu ₂ S ⁶	Li		150	100	10	~ 0.1	Coin cell
V ₂ O ₅ ⁷	Li	500	127	100		0.22	Coin cell
V ₂ O ₅ ²	Zn	50	370	12		1.2	Coin cell
VO2 8	Zn	5000	190	12	250	0.18	Coin cell
NT-COF ⁹	Li		100	100	100		Coin cell
Li _x TiO ₂	Li	47	240				Coin cell
nanoparticle ¹⁰							
C60@POC 11	Li		184	200	100	~1.0	Coin cell
MnO ₂ ¹²	Al	100	531	100	10	1.2	Coin cell
This work	Zn	500	216	100	200	0.98	Coin cell

Table S1. A summary of the important parameters and performance of the recently

reported photo-actuated batteries.

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